

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

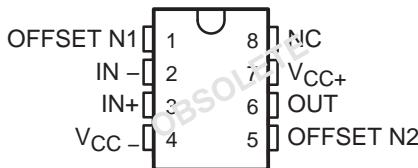
The TL087, TL088, and TL287 are obsolete and are no longer supplied.

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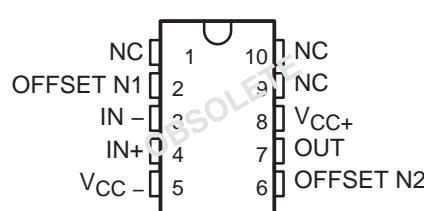
- Low Input Offset Voltage . . . 0.5 mV Max
- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- High Input Impedance . . . JFET-Input Stage

- Internal Frequency Compensation
- Latch-Up-Free Operation
- High Slew Rate . . . 18 V/ μ s Typ
- Low Total Harmonic Distortion 0.003% Typ

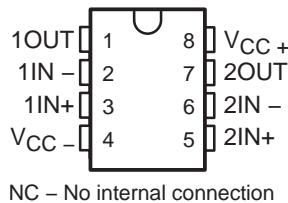
TL087, TL088
D, JG, OR P PACKAGE
(TOP VIEW)



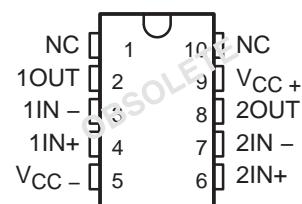
TL088M
U PACKAGE
(TOP VIEW)



TL287, TL288
JG OR P PACKAGE
(TOP VIEW)



TL288M
U PACKAGE
(TOP VIEW)



description/ordering information

These JFET-input operational amplifiers incorporate well-matched high-voltage JFET and bipolar transistors in a monolithic integrated circuit. They feature low input offset voltage, high slew rate, low input bias and offset currents, and low temperature coefficient of input offset voltage. Offset-voltage adjustment is provided for the TL087 and TL088.

The C-suffix devices are characterized for operation from 0°C to 70°C, and the I-suffix devices are characterized for operation from -40°C to 85°C. The M-suffix devices are characterized for operation over the full military temperature range of -55°C to 125°C.

ORDERING INFORMATION

T _A	TYPE	V _{IO} MAX AT 25°C	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	Dual	1 mV	PDIP (P)	Tube of 50	TL288CP	TL288CP

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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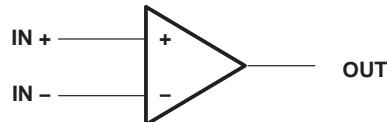
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symbol (each amplifier)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	TL088M TL288M	TL087I TL088I TL287I TL288I	TL087C TL088C TL287C TL288C	UNIT
Supply voltage, V _{CC} + (see Note 1)	18	18	18	V
Supply voltage, V _{CC} - (see Note 1)	-18	-18	-18	V
Differential input voltage (see Note 2)	±30	±30	±30	V
Input voltage (see Notes 1 and 3)	±15	±15	±15	V
Input current, I _I (each Input)	±1	±1	±1	mA
Output current, I _O (each output)	±80	±80	±80	mA
Total V _{CC} + terminal current	160	160	160	mA
Total V _{CC} - terminal current	-160	-160	-160	mA
Duration of output short circuit (see Note 4)	Unlimited	Unlimited	Unlimited	
Continuous total dissipation	See Dissipation Rating Table			
Maximum junction temperature, T _J		150	150	°C
Package thermal impedance, θ _{JA} (see Notes 5 and 6)	P package		85	85 °C/W
Lead temperature 1.6 mm (1/16 inch) from case for 60 seconds	JG or U package	300	300	300 °C
Storage temperature range, T _{stg}		-65 to 150	-65 to 150	-65 to 150 °C

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC} + and V_{CC} -.

2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
5. Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is PD = (T_J(max) - T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
6. The package thermal impedance is calculated in accordance with JESD 51-7.
7. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
8. Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is PD = (T_J(max) - T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
9. The package thermal impedance is calculated in accordance with JESD 51-7.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
U	675 mW	5.4 mW/°C	432 mW	351 mW	135 mW

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recommended operating conditions

			C-SUFFIX		I-SUFFIX		M-SUFFIX		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		±5	±5	±5	±5	±5	±15	V
V _{IC}	Common-mode input voltage	V _{CC} ± = ±5 V	-1	4	-1	4	-1	4	V
		V _{CC} ± = ±15 V	-11	11	-11	11	-11	11	
V _I	Input voltage	V _{CC} ± = ±5 V	-1	4	-1	4	-1	4	V
		V _{CC} ± = ±15 V	-11	11	-11	11	-11	11	
T _A	Operating free-air temperature		0	70	-40	85	-55	125	°C

operating characteristics $V_{CC} = \pm 15$ V, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TL088M, TL288M			TL087I, TL087C TL088I, TL088C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V _I = 10 V, C _L = 100 pF, AVD = 1	R _L = 2 kΩ, C _L = 100 pF, AVD = 1	18	8	18		V/μs
t _r	Rise time	V _I = 20 mV, C _L = 100 pF, AVD = 1	R _L = 2 kΩ, C _L = 100 pF, AVD = 1	55	55	55		ns
	Overshoot factor			25	25	25		%
V _n	Equivalent input noise voltage	R _S = 100 Ω, f = 1 kHz		19	19	19		nV/√Hz



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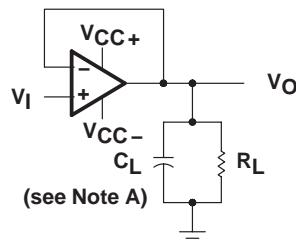
electrical characteristics, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS [†]	TL088M TL288M				TL087I TL088I TL287I TL288I				TL087C TL088C TL287C TL288C				UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	$R_S = 50 \Omega$, $V_O = 0$, $T_A = 25^\circ C$	TL087, TL287			0.1	0.5	0.1	0.5	0.1	0.5	0.1	0.5	mV
		$V_O = 0$, $T_A = 25^\circ C$	TL088, TL288	0.1	3	0.1	1	0.1	1	0.1	1	0.1	1	mV
α/V_{IO}	Temperature coefficient of input offset voltage	$R_S = 50 \Omega$, $T_A = 25^\circ C$	TL087, TL287	10	8	8	8	8	8	8	8	8	8	$\mu V/^\circ C$
I _{IO}	Input offset current	$T_A = 25^\circ C$		5		5	100	5	100	5	100	5	100	pA
I _{IB}	Input bias current [‡]	$T_A = 25^\circ C$		25		30	300	30	300	30	300	30	300	pA
V _{ICR}	Common-mode input voltage range	$T_A = 25^\circ C$		30		30	200	30	200	30	200	30	200	pA
V _{O(PP)}	Maximum-peak-to-peak output voltage swing	$T_A = 25^\circ C$, $R_L = 10 k\Omega$	TA = full range	100	$(V_{CC-} + 4$ to $V_{CC+} - 4$)	$(V_{CC-} + 4$ to $V_{CC+} - 4$)	$(V_{CC-} + 4$ to $V_{CC+} - 4$)	20	20	20	20	20	20	nA
AVD	Large-signal differential voltage amplification	$R_L \geq 2 k\Omega$, $T_A = 25^\circ C$	$V_O = \pm 10 V$, $R_L \geq 2 k\Omega$	24	27	24	27	24	27	24	27	24	27	V
B ₁	Unity-gain bandwidth	$R_L \geq 2 k\Omega$, $T_A = 25^\circ C$	$V_O = \pm 10 V$, $T_A = full range$	50	105	50	105	50	105	50	105	50	105	V/mV
r _f	Input resistance	$T_A = 25^\circ C$		25		25		25		25		25		MHz
CMRR	Common-mode rejection ratio	$R_S = 50 \Omega$, $V_{IC} = V_{ICR} \text{ min}$, $T_A = 25^\circ C$	$V_O = 0 V$, $T_A = 25^\circ C$	80	93	80	93	80	93	80	93	80	93	dB
k _{SVR}	Supply voltage rejection ratio ($\Delta V_{CC} \pm \Delta V_{IO}$)	$R_S = 50 \Omega$, $T_A = 25^\circ C$	$V_{CC\pm} = \pm 9 V$ to $\pm 15 V$, $T_A = 25^\circ C$	80	99	80	99	80	99	80	99	80	99	dB
I _{CC}	Supply current (per amplifier)	No load, $T_A = 25^\circ C$	$V_O = 0 V$, $T_A = 25^\circ C$	26	2.8	2.6	2.8	2.6	2.8	2.6	2.8	2.6	2.8	mA

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. Full range for T_A is $-55^\circ C$ to $125^\circ C$ for TL-88M;
 $-40^\circ C$ to $85^\circ C$ for TL-8; and $0^\circ C$ to $70^\circ C$ for TL-8-C.

[‡] Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes fixture capacitance.

Figure 1. Slew Rate, Rise/Fall Time, and Overshoot Test Circuit

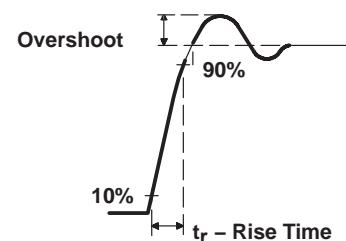


Figure 2. Rise Time and Overshoot Waveform

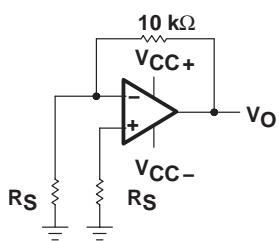


Figure 3. Noise Voltage Test Circuit

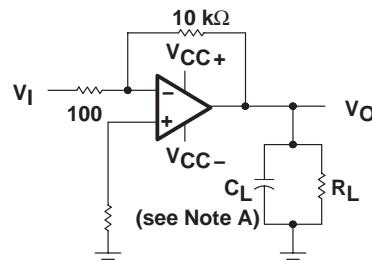


Figure 4. Unity-Gain Bandwidth and Phase Margin Test Circuit

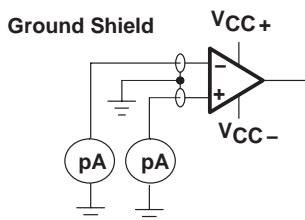


Figure 5. Input Bias and Offset Current Test Circuit

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typical values

Typical values as presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoamp bias current level typical of these JFET operational amplifiers, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied, but with no device in the socket. The device then is inserted in the socket and a second test that measures both the socket leakage and the device input bias current is performed. The two measurements then are subtracted algebraically to determine the bias current of the device.



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TYPICAL CHARACTERISTICS

table of graphs

			FIGURE
α_{VIO}	Temperature coefficient of input offset voltage	Distribution	6, 7
I_{IO}	Input offset current	vs Temperature	8
I_{IB}	Input bias current	vs V_{IC} vs Temperature	9 8
V_I	Common-mode input voltage range limits	vs V_{CC} vs Temperature	10 11
V_{ID}	Differential input voltage	vs Output voltage	12
V_{OM}	Maximum peak output voltage swing	vs V_{CC} vs Output current vs Frequency vs Temperature	13 17 14, 15, 16 18
A_{VD}	Differential voltage amplification	vs R_L vs Frequency vs Temperature	19 20 21
z_o	Output impedance	vs Frequency	24
CMRR	Common-mode rejection ratio	vs Frequency vs Temperature	22 23
k_{SVR}	Supply-voltage rejection ratio	vs Temperature	25
I_{OS}	Short-circuit output current	vs V_{CC} vs Time vs Temperature	26 27 28
I_{CC}	Supply current	vs V_{CC} vs Temperature	29 30
SR	Slew rate	vs R_L vs Temperature	31 32
	Overshoot factor	vs C_L	33
V_n	Equivalent input noise voltage	vs Frequency	34
THD	Total harmonic distortion	vs Frequency	35
B_1	Unity-gain bandwidth	vs V_{CC} vs Temperature	36 37
ϕ_m	Phase margin	vs V_{CC} vs C_L vs Temperature	38 39 40
	Phase shift	vs Frequency	20
	Pulse response	Small-signal Large-signal	41 42

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TYPICAL CHARACTERISTICS[†]

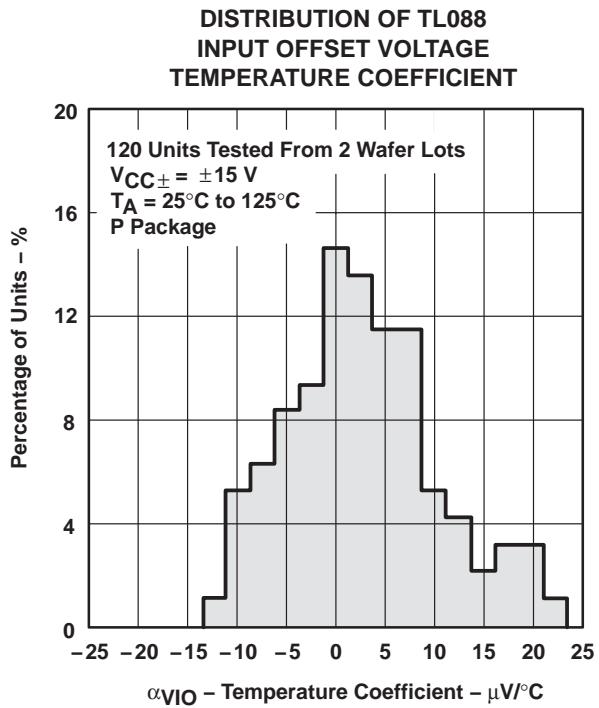


Figure 6

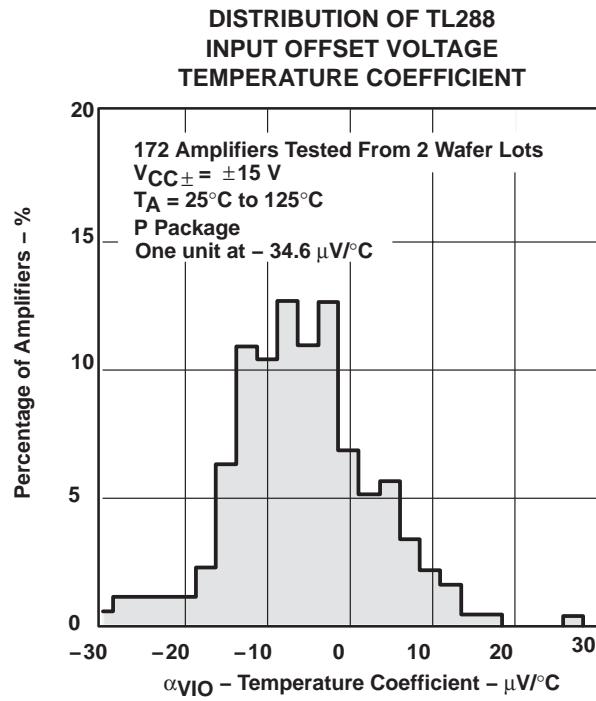


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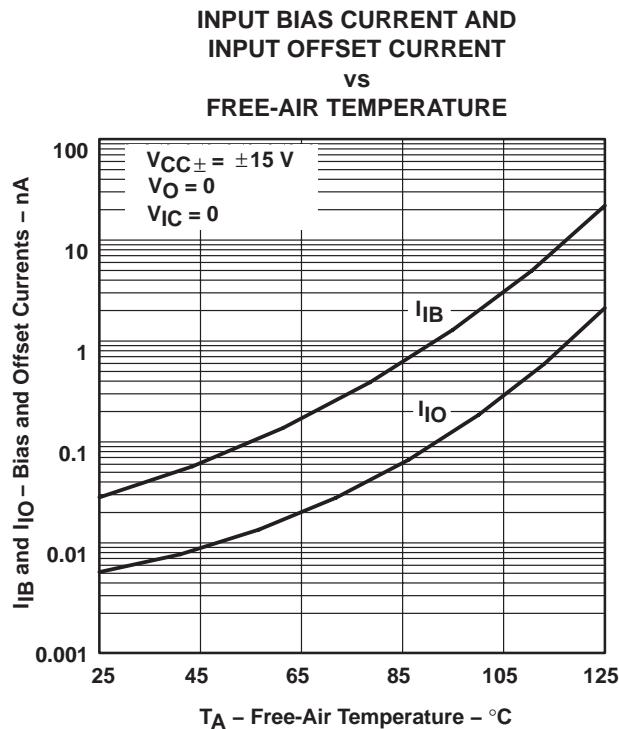


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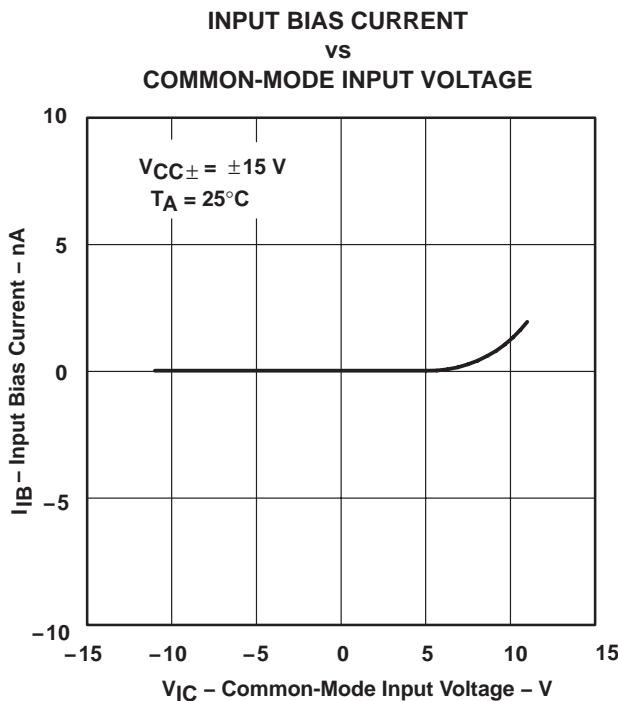


Figure 9

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

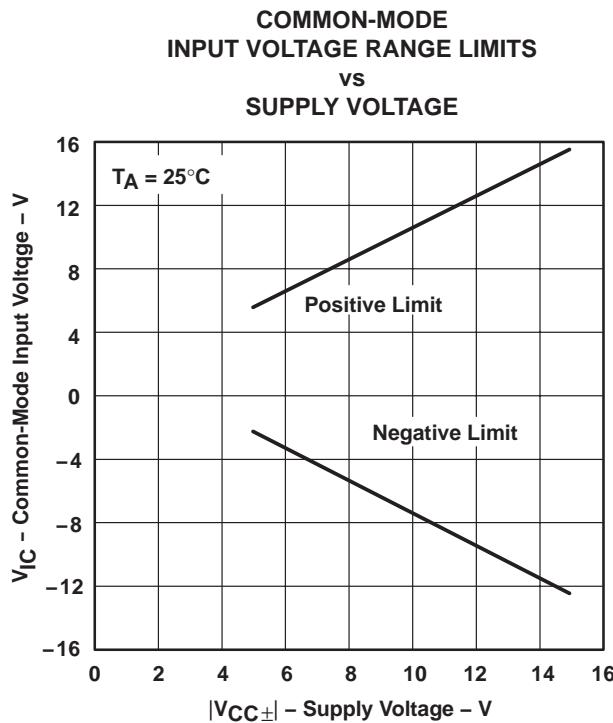


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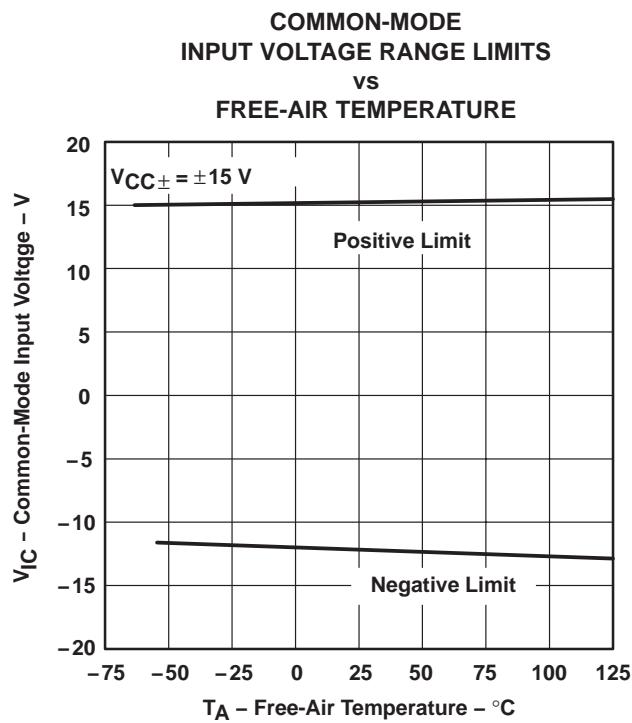


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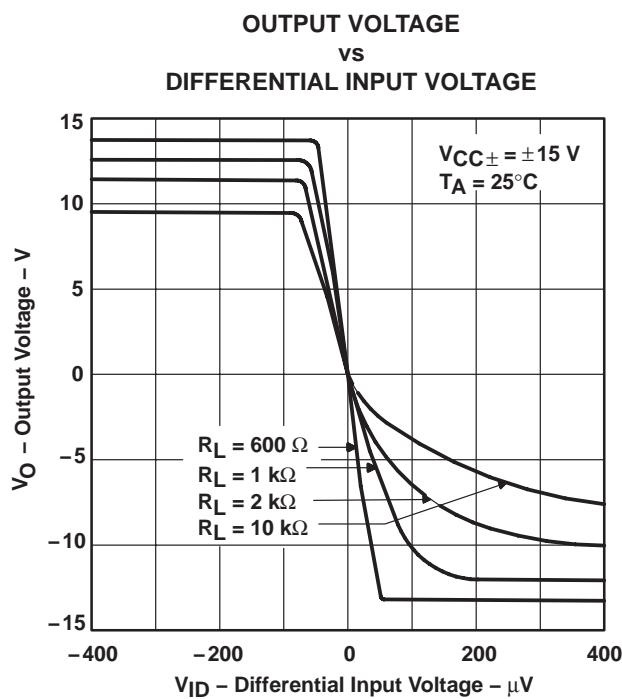


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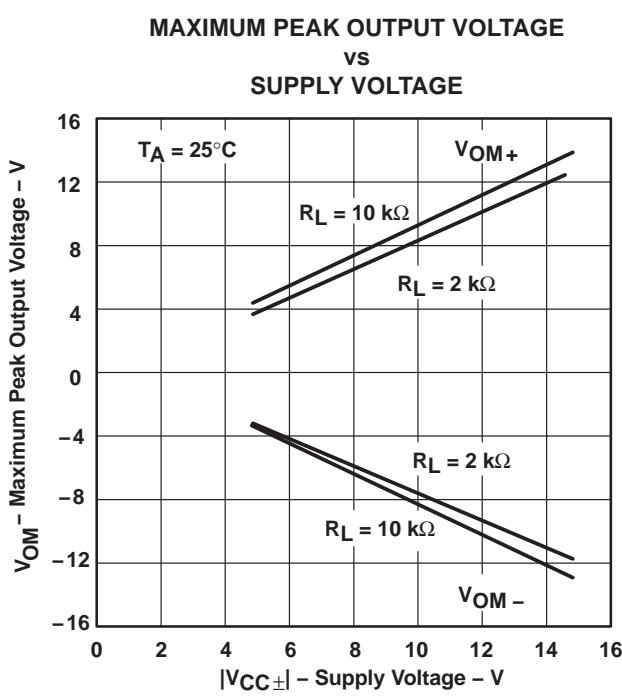


Figure 13

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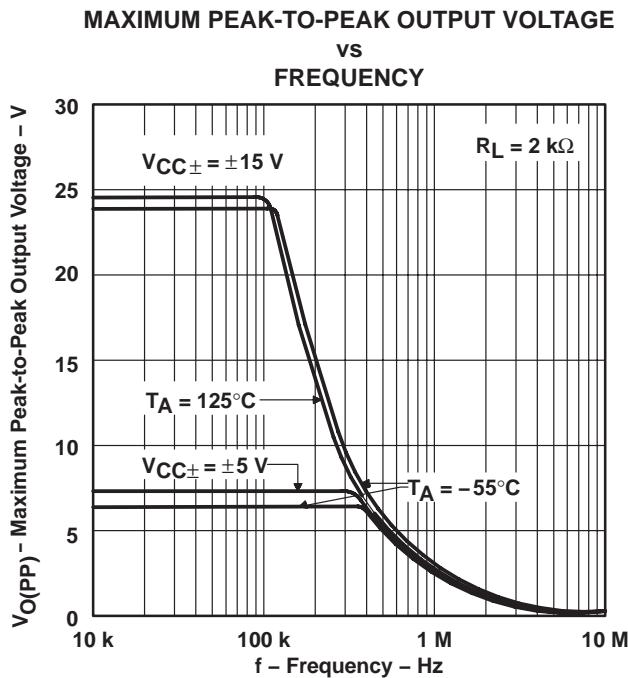


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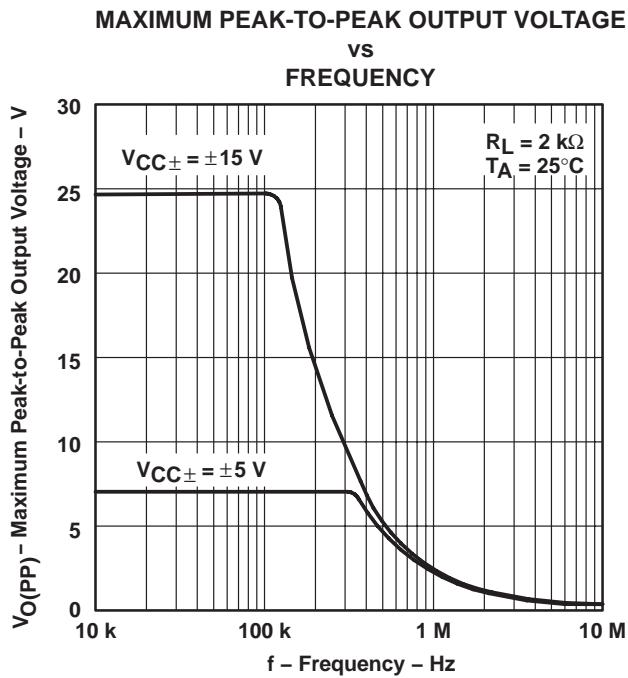


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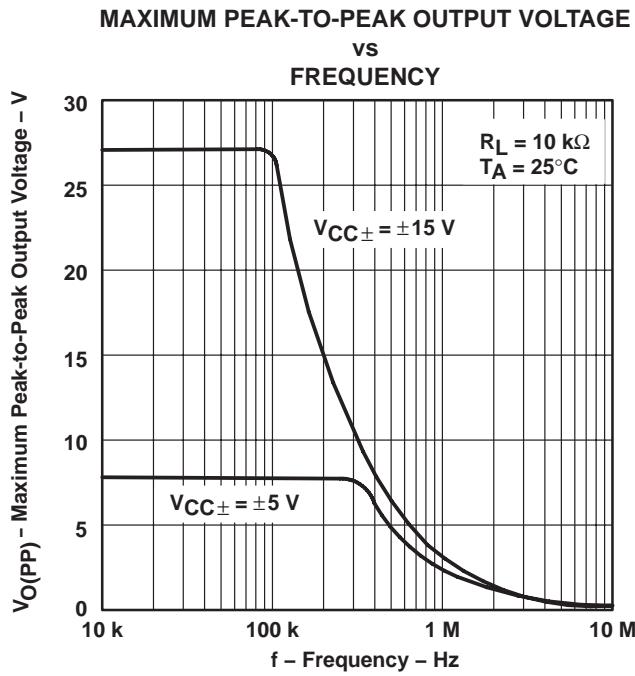


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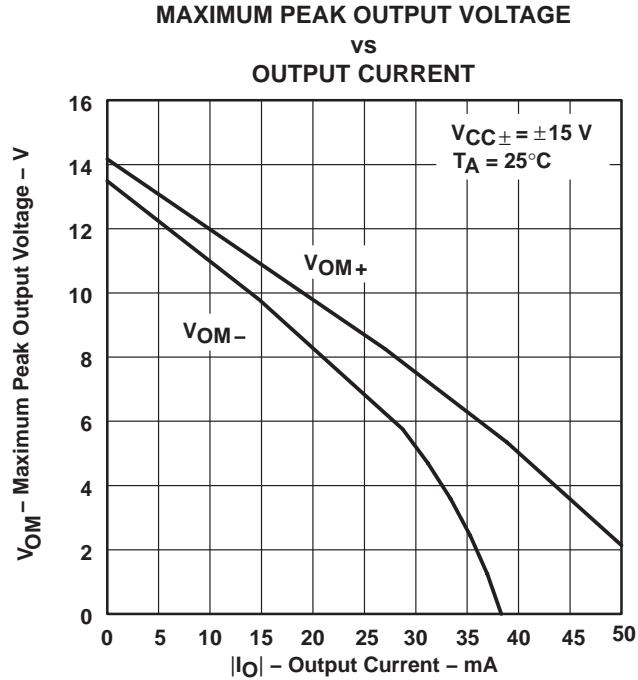


Figure 17

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

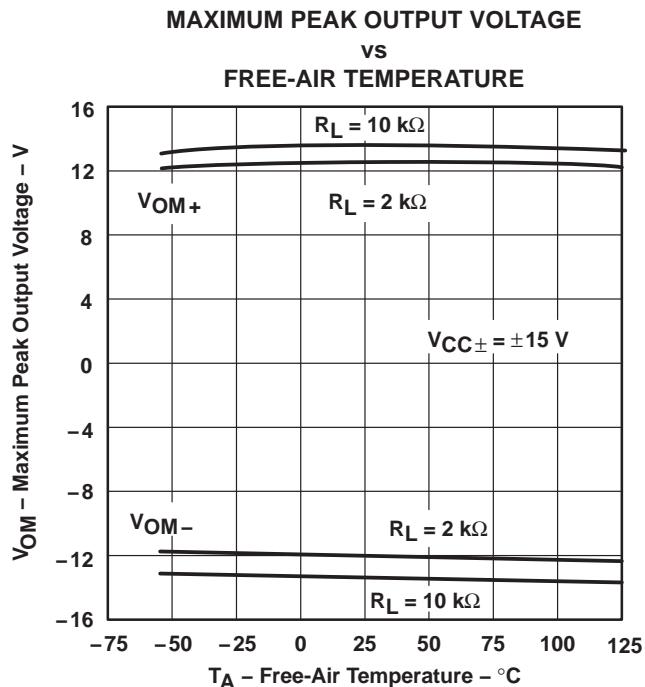


Figure 18

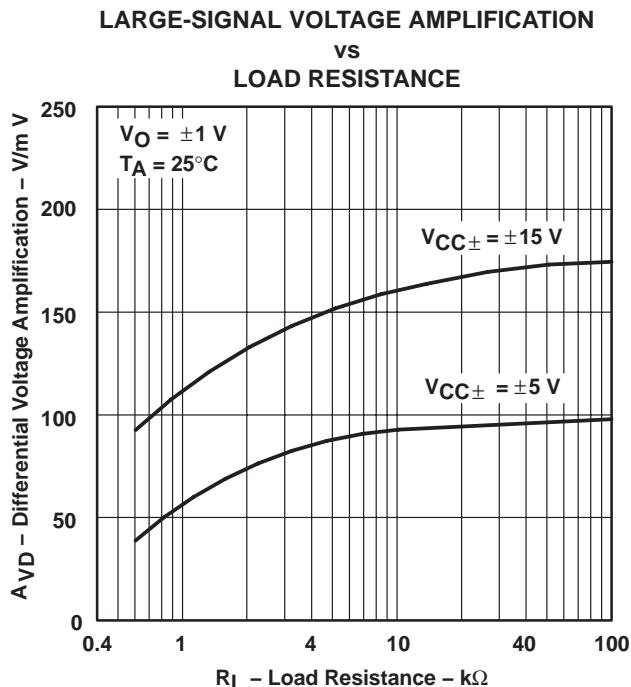


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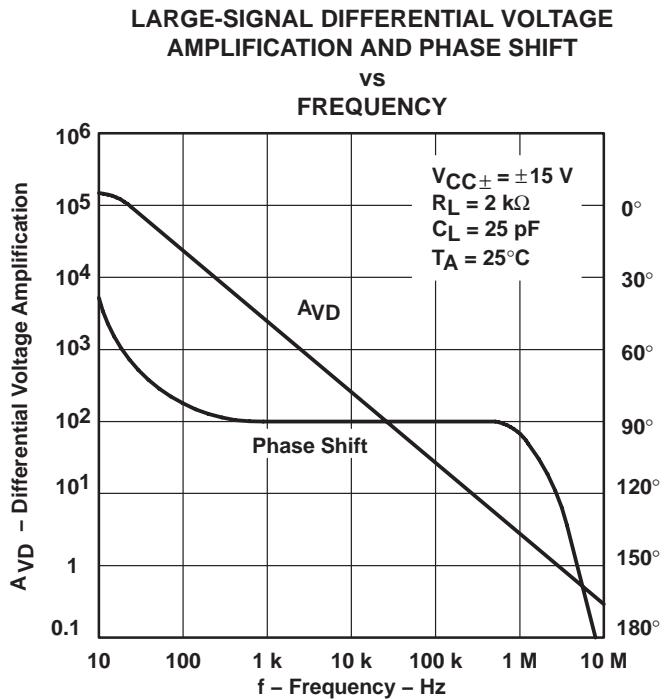


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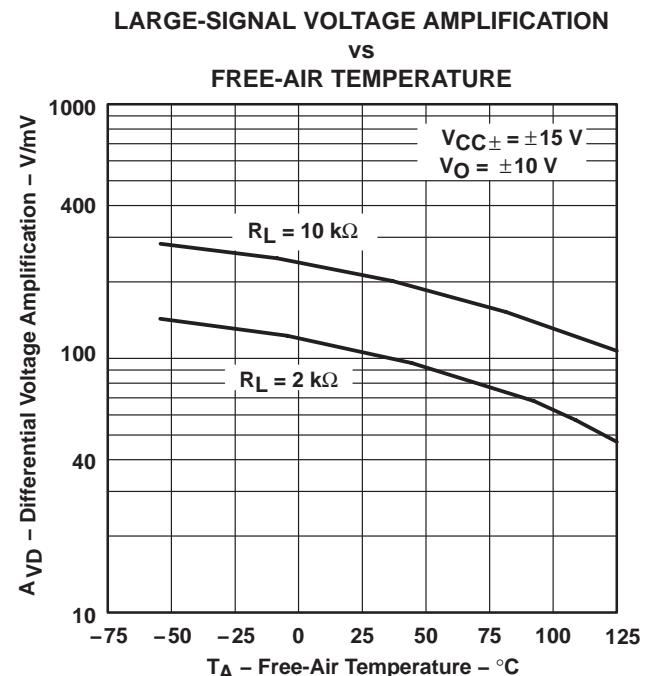


Figure 21

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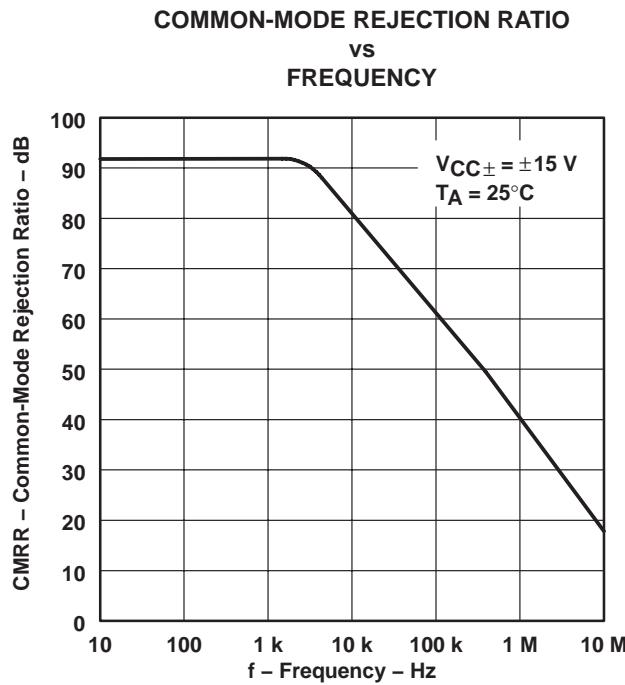


Figure 22

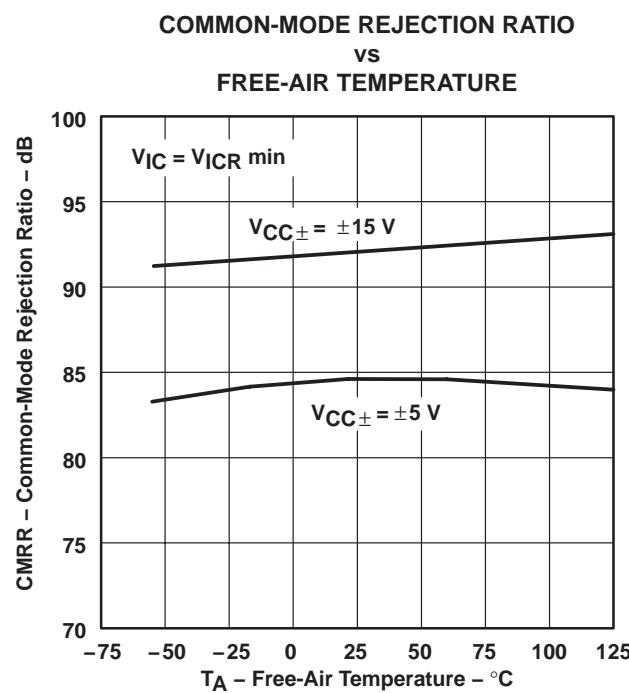


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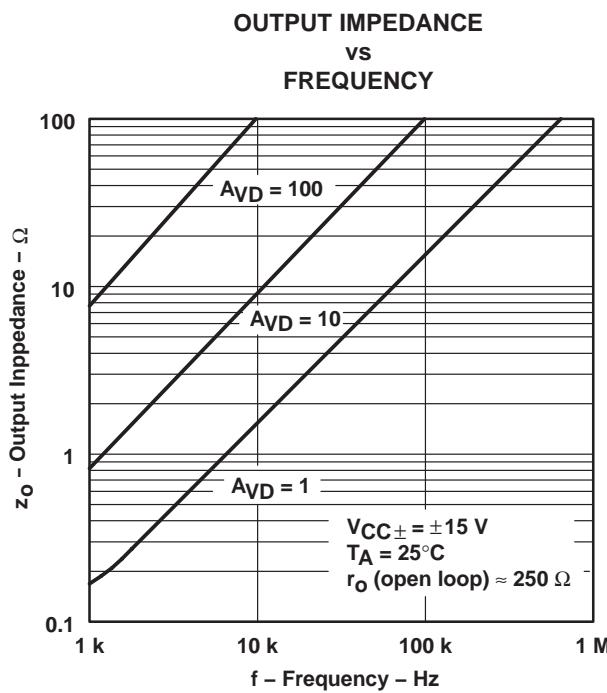


Figure 24

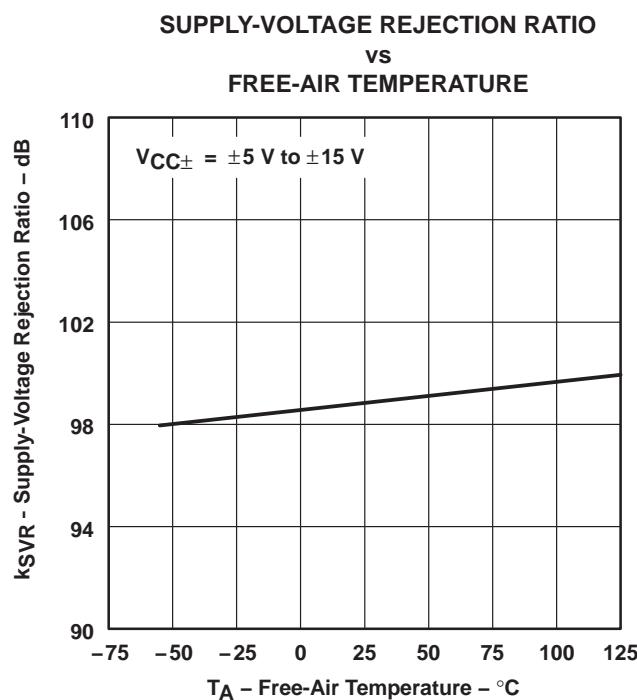


Figure 25

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

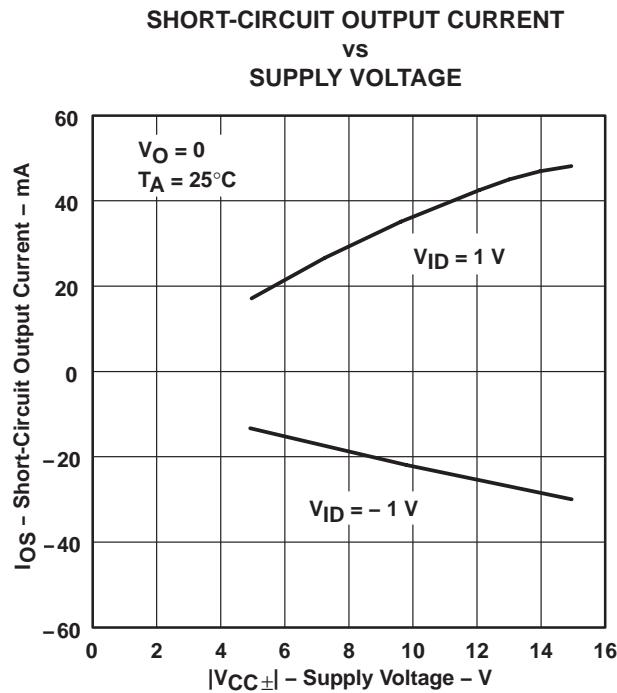


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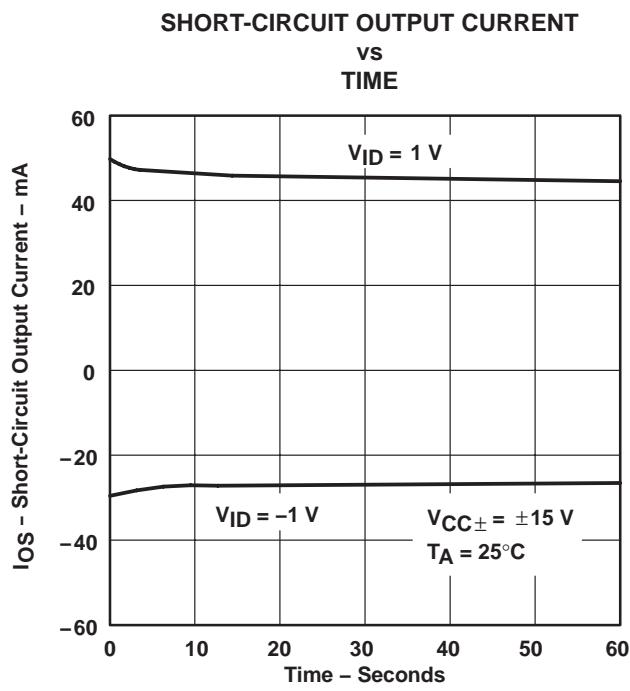


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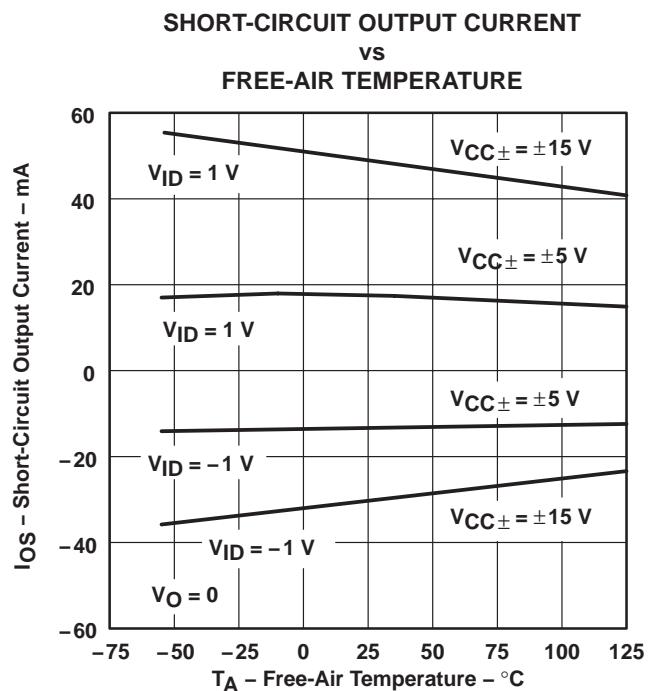


Figure 28

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS†

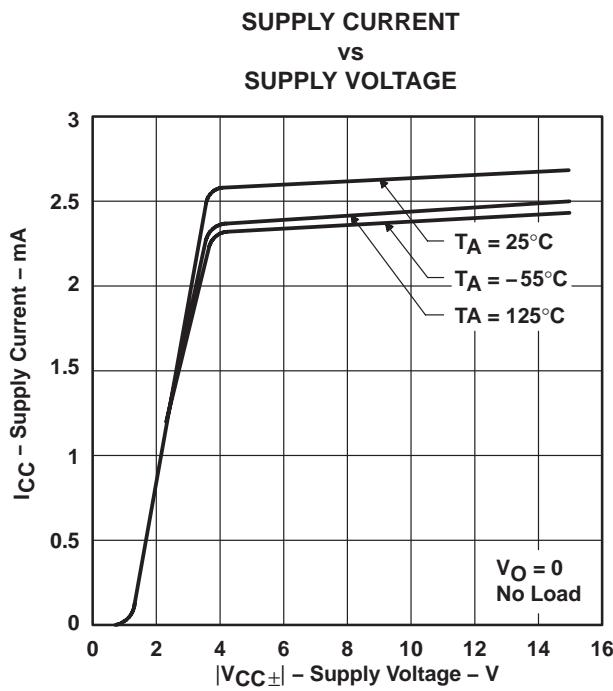


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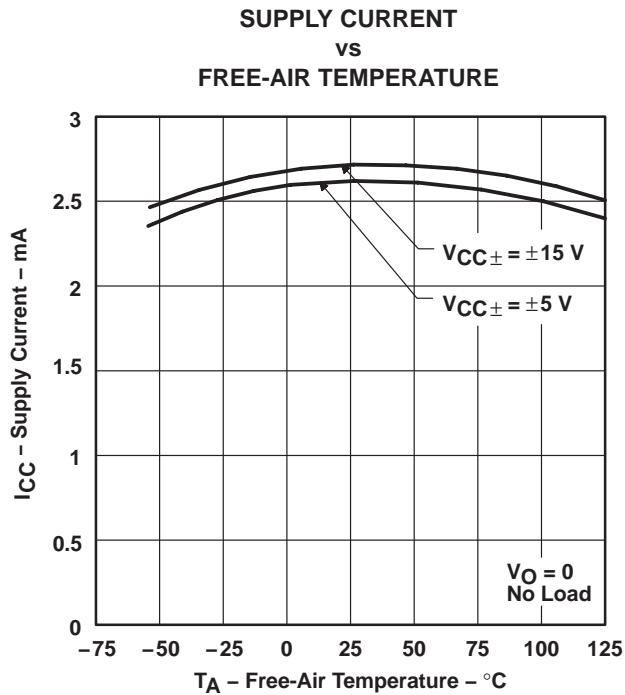


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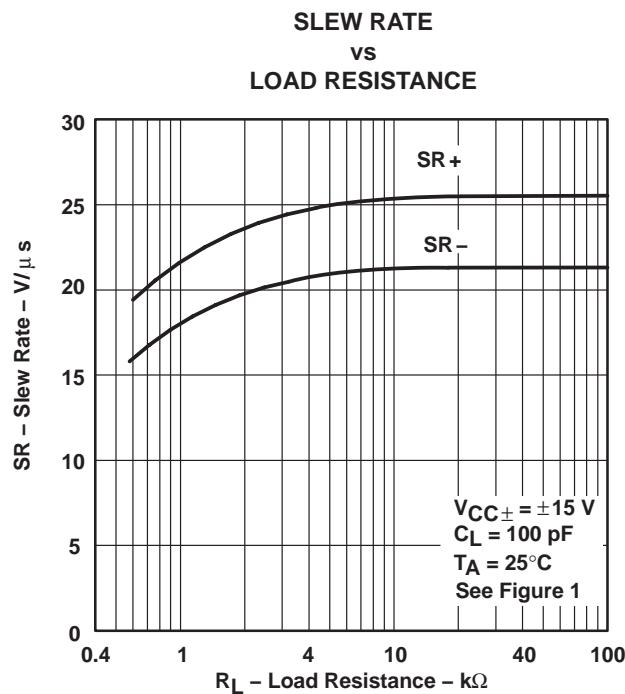


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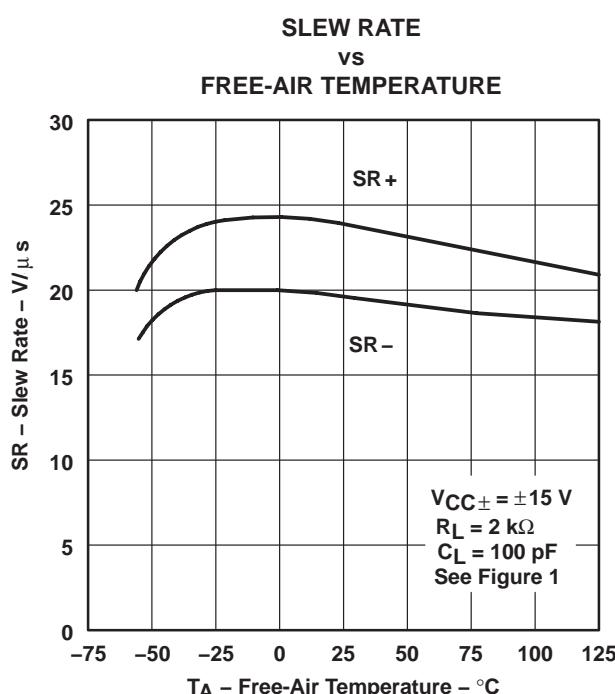


Figure 32

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

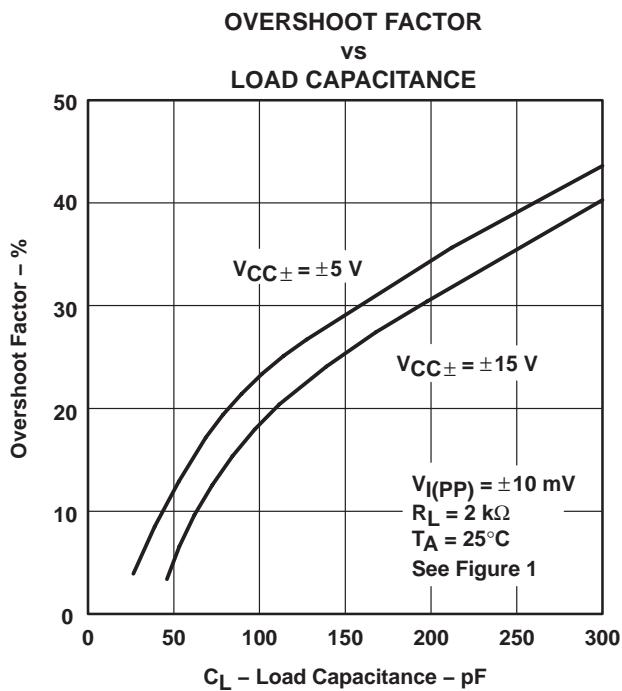


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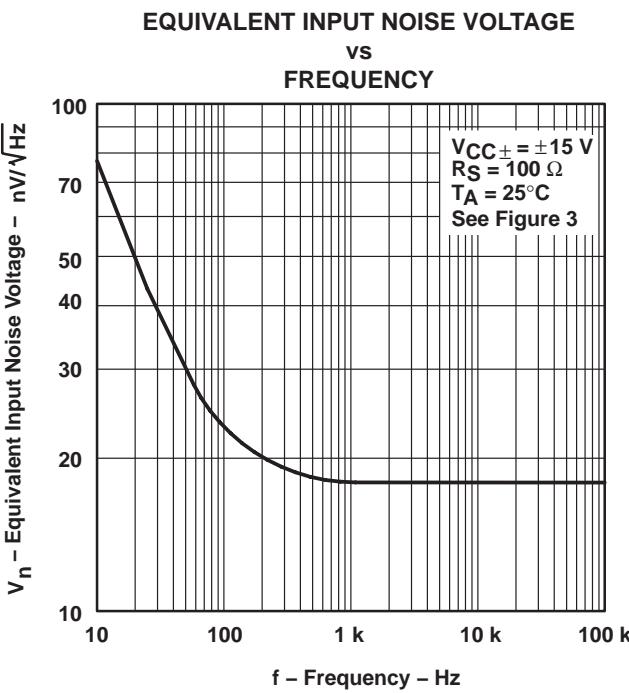


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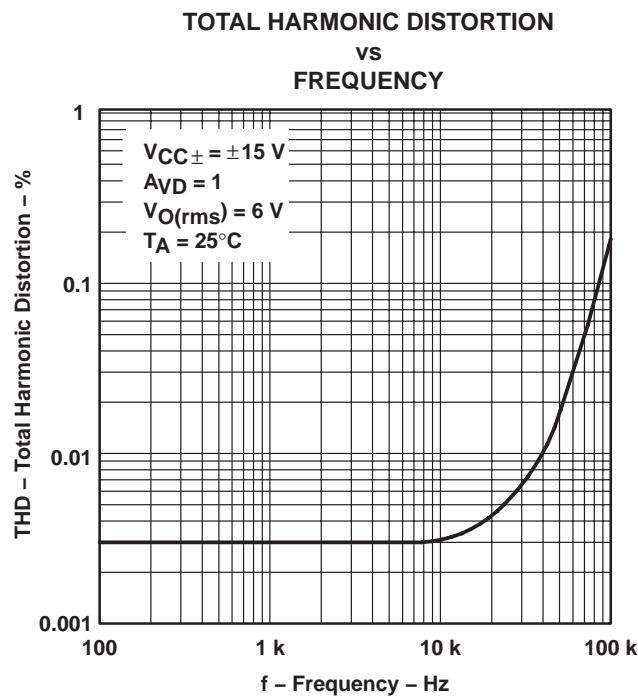


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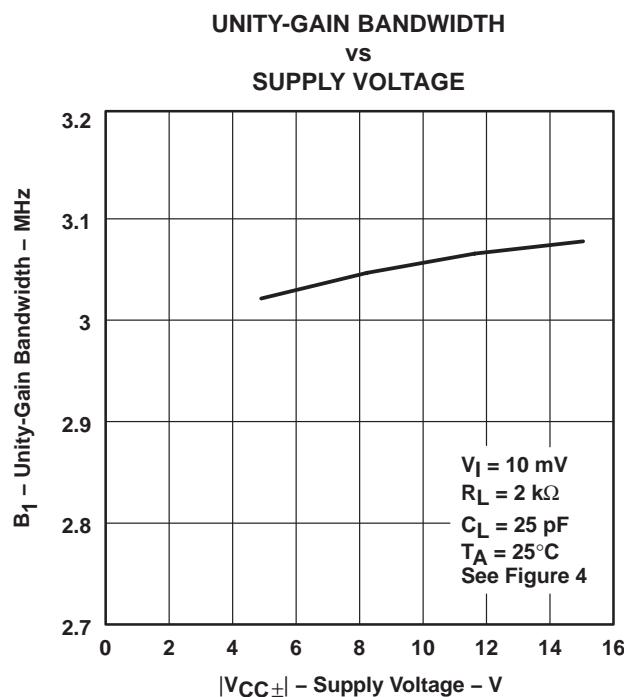


Figure 36

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TYPICAL CHARACTERISTICS[†]

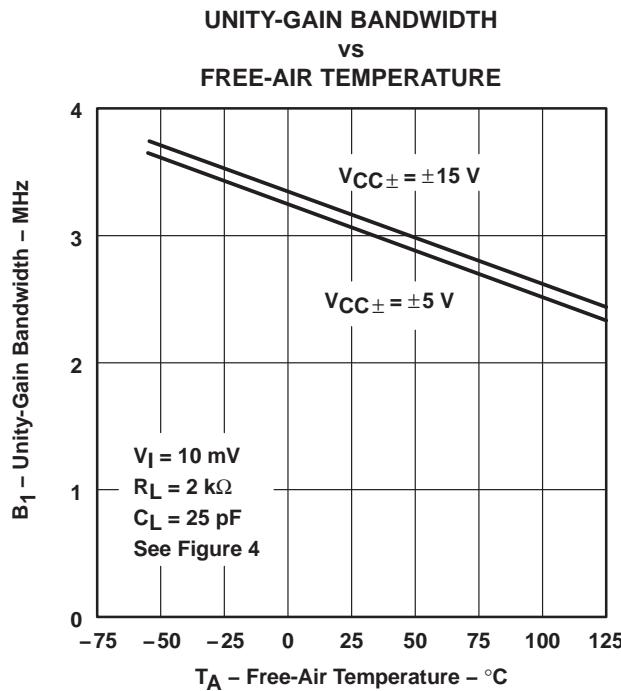


Figure 37

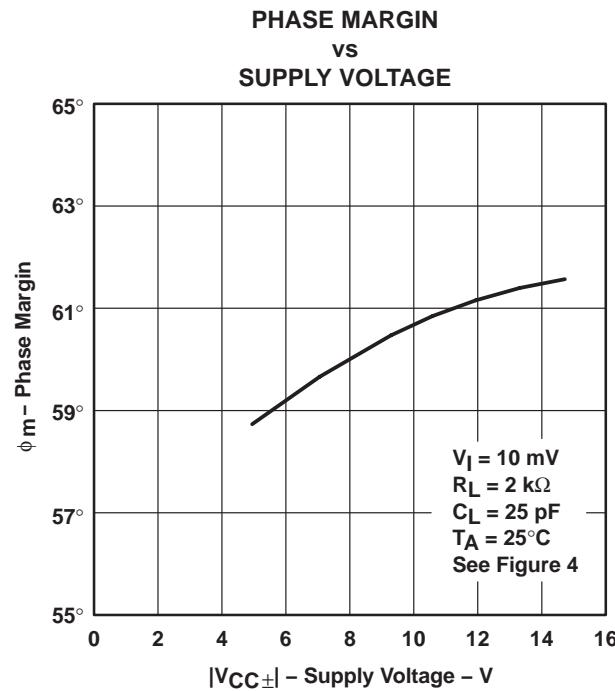


Figure 38

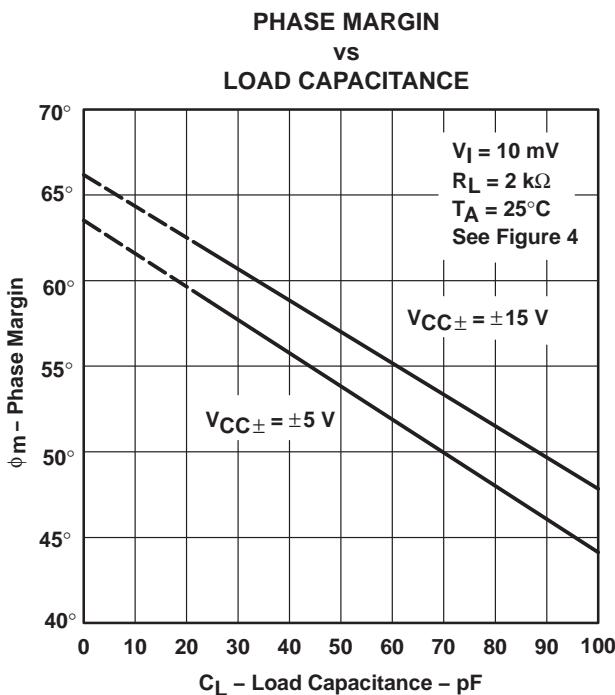


Figure 39

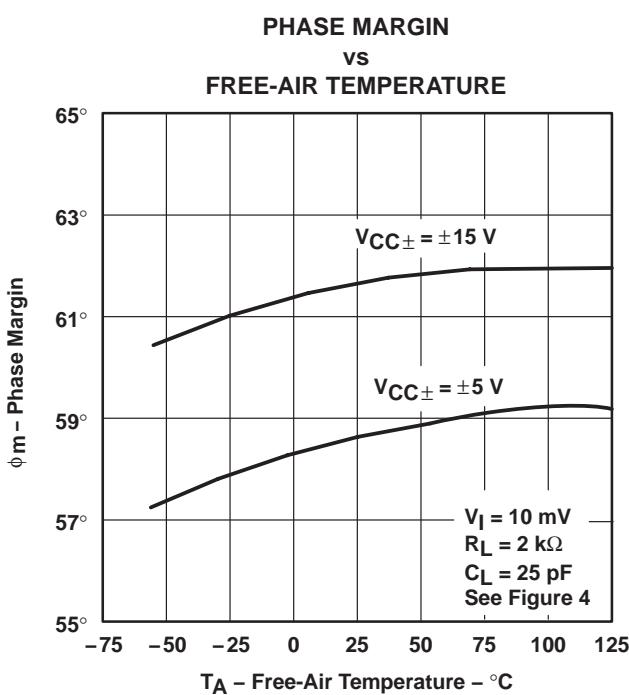


Figure 40

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER
SMALL-SIGNAL
PULSE RESPONSE

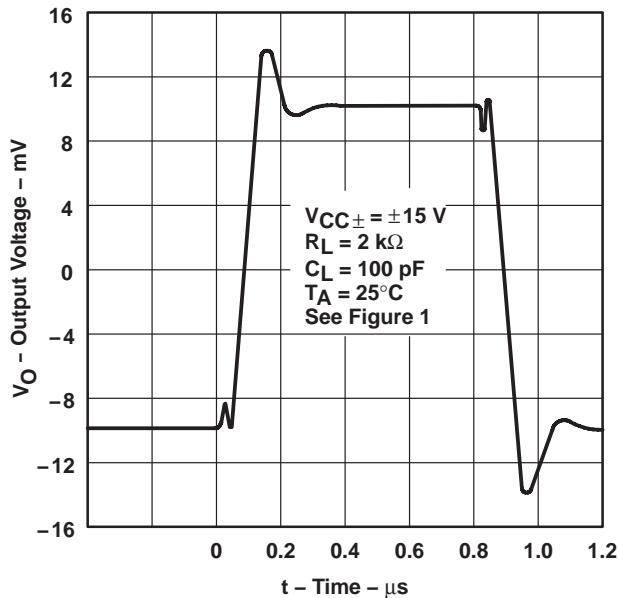


Figure 41

VOLTAGE-FOLLOWER
LARGE-SIGNAL
PULSE RESPONSE

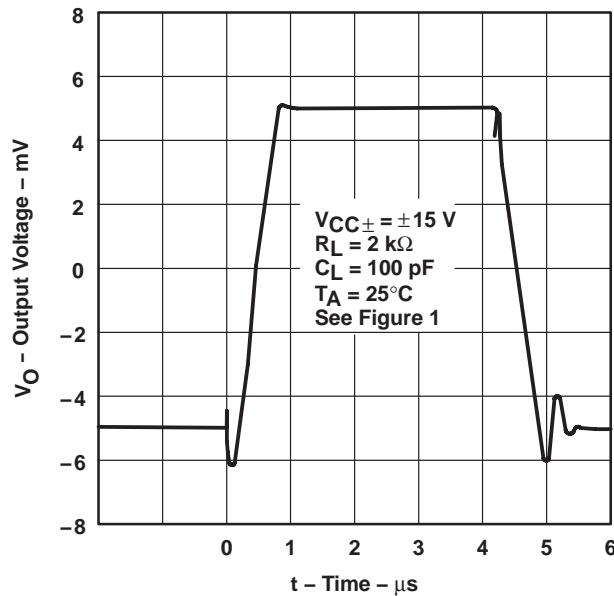


Figure 42

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

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TYPICAL APPLICATION DATA

output characteristics

All operating characteristics are specified with 100-pF load capacitance. These amplifiers will drive higher capacitive loads; however, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or even oscillation. The value of the load capacitance at which oscillation occurs varies with production lots. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem. Capacitive loads of 1000 pF, and larger, may be driven if enough resistance is added in series with the output (see Figure 43).

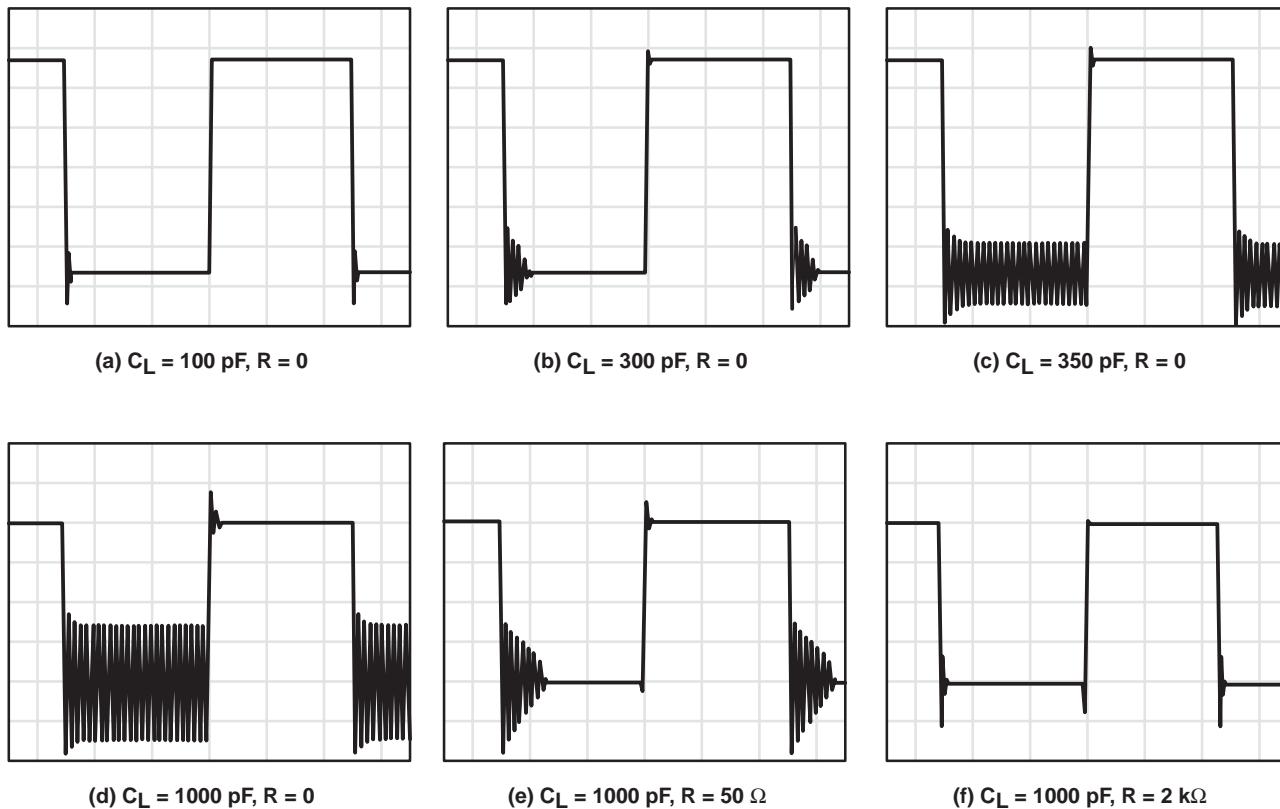


Figure 43. Effect of Capacitive Loads

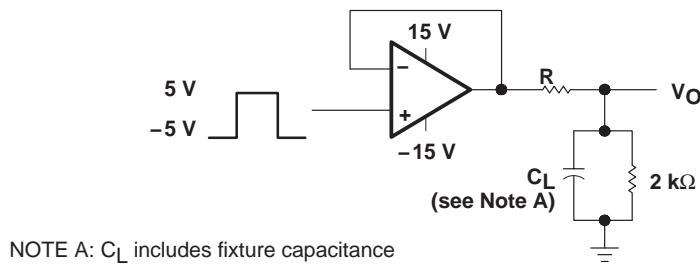


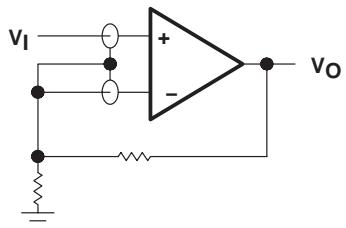
Figure 44. Test Circuit for Output Characteristics

TYPICAL APPLICATION DATA

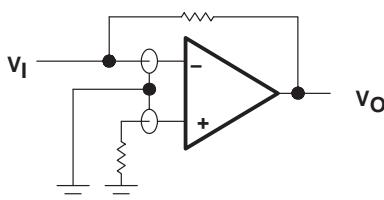
input characteristics

These amplifiers are specified with a minimum and a maximum input voltage that, if exceeded at either input, could cause the device to malfunction.

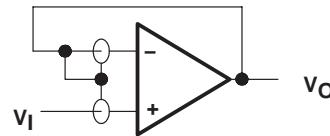
Because of the extremely high input impedance and resulting low bias current requirements, these amplifiers are well suited for low-level signal processing; however, leakage currents on printed circuit boards and sockets easily can exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 45). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.



(a) NONINVERTING AMPLIFIER



(b) INVERTING AMPLIFIER



(c) UNITY-GAIN AMPLIFIER

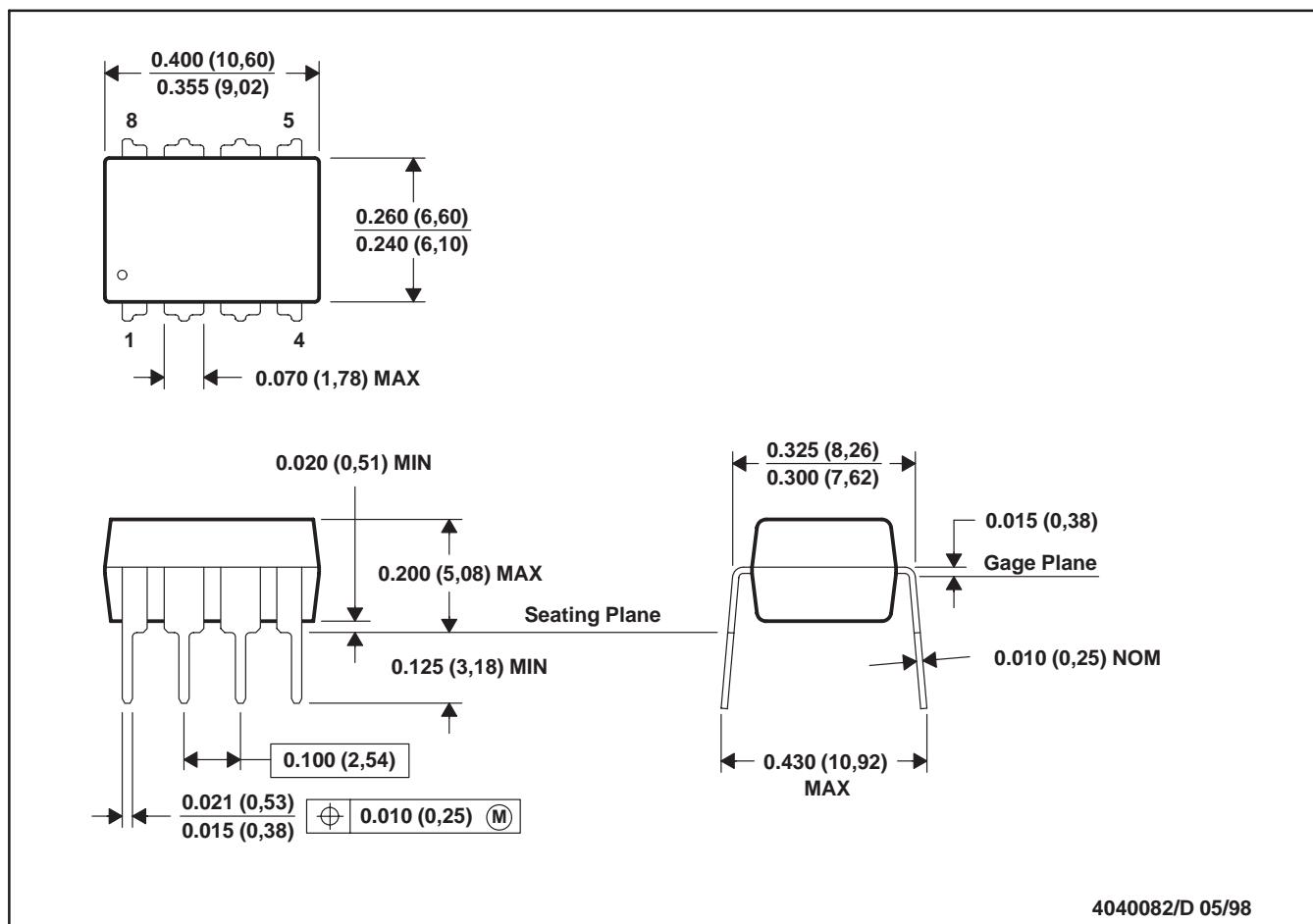
Figure 45. Use of Guard Rings

noise performance

The noise specifications in operational amplifier circuits are greatly dependent on the current in the first-stage differential amplifier. The low input bias current requirements of these amplifiers result in a very low current noise. This feature makes the devices especially favorable over bipolar devices when using values of circuit impedance greater than 50 k Ω .

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

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